

# HSCH-9161 HSCH-9162 GaAs Detector Diode

# **Data Sheet**

### **Description**

The HSCH-916x is a discrete, beam lead, GaAs diode fabricated using the modified barrier integrated diode (MBID) process.

### **Applications**

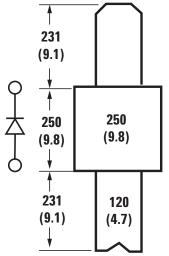
This diode is suitable for medium– low barrier, zero bias detector applications. The HSCH-916x is functional through W-band (110 GHz) and can be mounted in microstrip, finline, and coplanar circuits.

#### **Assembly Techniques**

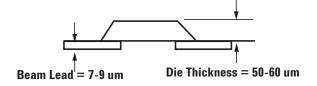
Diodes are ESD sensitive. ESD preventive measures must be employed in all aspects of storage, handling, and assembly. Diode ESD precautions, handling considerations, and bonding methods are critical factors in successful diode performance and reliability.

Agilent application note #55, "Beam Lead Diode Bonding and Handling Procedures" provides basic information on these subjects.

Additional References: PN# 2, "TC611 Diode Model," and PN# 12, "TC611 GaAs Detector Diode Sensitivity Measurements."



# Note: All dimensions in microns (mils)



#### **Features**

- Low Junction Capacitance
- fc >200 GHz
- Lower Temperature Coefficient than Silicon
- Durable Construction
  - -Typical 6 gram beam lead strength
  - -High power handling capability

# **Absolute Maximum Ratings**

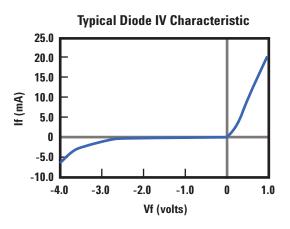
| Symbol           | Parameters/Conditions | Min. | Тур. | Max. | Units |
|------------------|-----------------------|------|------|------|-------|
| $T_{op}$         | Operating Temp. Range | -65  |      | 150  | °C    |
| T <sub>stg</sub> | Storage Temp. Range   | -65  |      | 200  | °C    |
| $\overline{P_B}$ | Burnout Power         |      | 20   |      | dBm   |



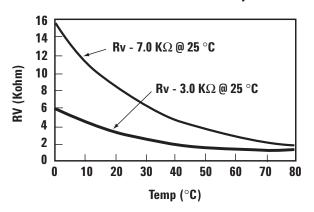
# DC Specifications/Physical Properties ( $T_A = 25$ °C)

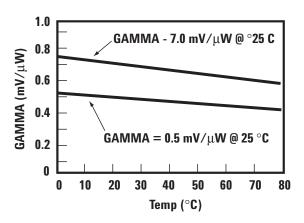
|             |                  | / \                      |      |                                |      |                       |       |
|-------------|------------------|--------------------------|------|--------------------------------|------|-----------------------|-------|
| Part Number | Junction         | Video<br>Resistance (kW) |      | Voltage Sensitivity<br>(mV/mW) |      | Beam Lead<br>Strength |       |
|             | Capacitance (pF) |                          |      |                                |      |                       |       |
|             | Typical          | Min.                     | Max. | Min.                           | Typ. | Max.                  | Unit  |
| HSCH-9161   | .035             | 2.5                      | 7.5  | 0.5                            |      | 3                     | grams |
| HSCH-9162   | .035             | 1.8                      | 7.5  | 0.5                            |      | 3                     | grams |

# **Typical Diode IV Characteristic**



# **Diode Parameter Variation with Temperature**





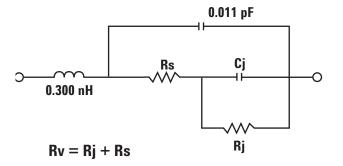
DC measurement assumes  $50\Omega$  load; ideal diode would be  $1mV/\mu W,$ 

Note: Each line represents a different value of RV oe Gamma at room temperature.

**Typical Small Signal Parameters as a Function of Bias** 

| _            | Bias Voltage |           |       |       |  |  |
|--------------|--------------|-----------|-------|-------|--|--|
| Parameter    |              |           |       |       |  |  |
|              | -4.0V        | Zero Bias | +0.1V | +0.5V |  |  |
| $Rs(\Omega)$ | 20           | 20        | 20    | 20    |  |  |
| $Rj(\Omega)$ | 440          | 3000      | 277   | 34    |  |  |
| Cj(pF)       | 0.019        | 0.035     | 0.027 | 0.034 |  |  |

Note: Parameter values extracted from 26–40 GHz s–parameter data @ –20 dBm.



This data sheet contains a variety of typical and guaranteed performance data. The information supplied should not be interpreted as a complete list of circuit specifications. Customers considering the use of this, or other WPTC GaAs ICs, for their design should obtain the current production specifications from WPTC Marketing. In this data sheet the term typical refers to the 50th percentile performance. For additional information contact WPTC Marketing at 707-577-4482.

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